

Si9988

Vishay Siliconix

Buffered H-Bridge Driver with Integrate MOSFET

DESCRIPTION

The Si9988 is an integrated, buffered H-bridge with TTL compatible inputs and the capability of delivering a continuous 0.65 A at $V_{DD} = 5$ V (room temperature) at switching rates up to 200 kHz. Internal logic prevents the upper and lower outputs of either half-bridge from being turned on simultaneously. Both outputs may be forced low (for motor braking) by pulling \overline{EN} to logic high.

The Si9988 is available in both standard and lead (Pb)-free, 8-pin TSSOP packages, specified to operate over a voltage range of 3.8 V to 13.2 V, and the industrial temperature range of - 40 $^{\circ}$ C to 85 $^{\circ}$ C (D suffix).

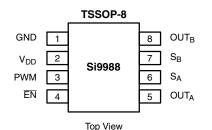
FEATURES

- 0.65 A H-bridge
- 200 kHz switching rate
- Shoot-through limited
- TTL compatible inputs
- 3.8 V to 13.2 V operating range
- Surface mount packaging
- Total R_{DS(on)} for N- and P-channel:
 1.8 at V_{DD} = 4.5 V and T_A = 85 °C0.65 A H-bridge

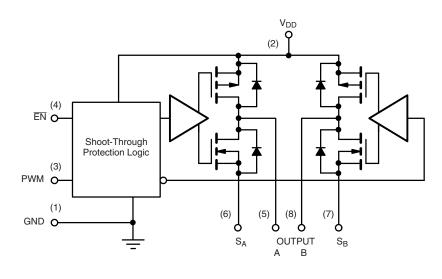
APPLICATIONS

- VCM driver
- Brushed motor driver
- Stepper motor driver
- Power converter
- · Optical disk drives
- · Power supplies
- High performance servo

FUNCTIONAL BLOCK DIAGRAM, PIN CONFIGURATION AND TRUTH TABLE



TRUTH TABLE						
EN	PWM	OUT _A	OUTB			
0	0	0	1			
0	1	1	0			
1	0	0	0			
1	1	0	0			



ORDERING INFORMATION						
Part Number	Marking	Temperature Range	Package			
Si9988DQ-T1	988	- 40 °C to 85 °C	Tape and reel			
Si9988DQ-T1-E3	900	- 40 C 10 85 C	Tape and teel			

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ABSOLUTE MAXIMUM RATINGS ^a					
Parameter		Limit	Unit		
V _{DD}		15			
Voltage on any Pin with Respect to Ground		- 0.3 to V _{DD} + 0.3	v		
Voltage on Pins 5, 8 with Respect to Ground		- 1 to V _{DD} + 1			
Voltage on Pins 6, 7		- 0.3 to GND + 1			
Peak Output Current		1	A		
Storage Temperature		- 65 to 150	°C		
Junction Temperature (T _J)		150			
Continues I. Current (T. 125 °C V. 5 V) $T_A = 25 °C$		0.67			
Continuos I _{out} Current (T _J = 135 °C, Y _{DD} = 5 V)	T _A = 85 °C	0.47	— A		
Power Dissipation ^b	·	0.83	W		
θ _{JA}		120	°C/W		
Operating Temperature Range		- 40 to 85	°C		

Notes:

a. Device mounted with all leads soldered or welded to PC board.

b. Derate 8.3 mW/°C above 25 °C. c. $T_J = T_A + (P_D)(\theta_{JA})$, $P_D =$ power dissipation.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING RANGE					
Parameter	Limit	Unit			
V _{DD}	3.8 to 13.2	V			
Maximum Junction Temperature (T _J)	135	°C			

SPECIFICATIONS				[<u> </u>		
Parameter	Symbol	Test Conditions Unless Otherwise Specified $V_{DD} = 3.8$ to 13.2 V S_A at GND, S_B at GND		Limits D Suffix, - 40 °C to 85 °C			Unit
raiametei	Symbol			Min ^a	Тур ^ь	Max ^a	onit
Input (EN, PWM)							
Input Voltage High	V _{INH}			2			v
Input Voltage Low	V _{INL}					1	v
Input Current with Input Voltage High	I _{INH}	V _{IN} = 13.	2 V			1	
Input Current with Input Voltage Low	I _{INL}	V _{IN} = 0	V	- 1			μA
Output		•			•		
			V _{DD} = 10.8 V	10.55	10.70		
Output Voltage High ^c	V _{OUTH}	I _{OUT} = - 300 mA	V _{DD} = 4.5 V	4.20	4.35		
			V _{DD} = 3.8 V	3.40	3.62		v
			V _{DD} = 10.8 V		0.09	0.20	v
Output Voltage Low ^c	V _{OUTL}	I _{OUT} = 300 mA	V _{DD} = 4.5 V		0.12	0.25	
			V _{DD} = 3.8 V		0.14	0.30	
Output V Clamp High	V _{CLH}	EN = PWM ≥ 2 V	I _{OUT} = 100 mA		V _{DD} + 0.7	V _{DD} + 1.0	V
Output V Clamp Low	V _{CLL}	$EIN = PVVIVI \ge 2 V$	I _{OUT} = - 100 mA	- 1.0	- 0.7		v
Supply			•			· · · · · ·	
		EN = 0 V, PWM = 100 kHz, V _{DD} = 5 V			1.0	1.5	mA
V _{DD} Supply Current	I _{DD}	EN = 4.5 V, PWM = 100) kHz, V _{DD} = 5.5 V		60	140	
		<u>EN</u> = PWM = 4.5 V, V _{DD} = 5.5 V			55	110	μA

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SPECIFICATIONS							
Parameter	Symbol	Test Conditions Unless Otherwise Specified	Limits D Suffix, - 40 °C to 85 °C			Unit	
	ey	$V_{DD} = 3.8 V \text{ to } 13.2 V$ S _A at GND, S _B at GND	Min ^a	Тур ^ь	Max ^a	- Crint	
Dynamic							
Propagation Dolov, OUT d	T _{PLH}	V _{DD} = 5 V, EN = 0 V		300			
Propagation Delay - OUT _A d	T _{PHL}			115			
Propagation Dalay OUT d	T _{PLH}			75		nS	
Propagation Delay - OUT _B ^d	T _{PHL}			330			
Break-Before-Make ^d	BBM _{PLH}			225			
	BBM _{PHL}			215			

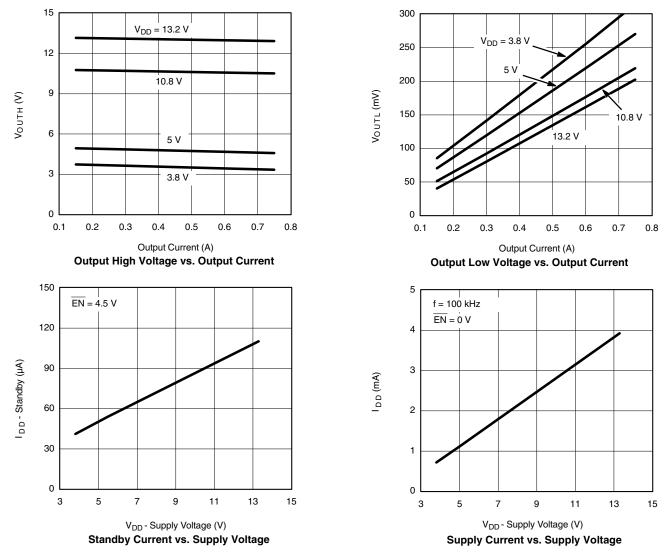
Notes:

a. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet. b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing, measured $T_A = 25$ °C.

c. Min and Max value measured at $T_{.1} = 135$ °C.

d. PLH = PWM low to high, PHL = PWM high to low.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



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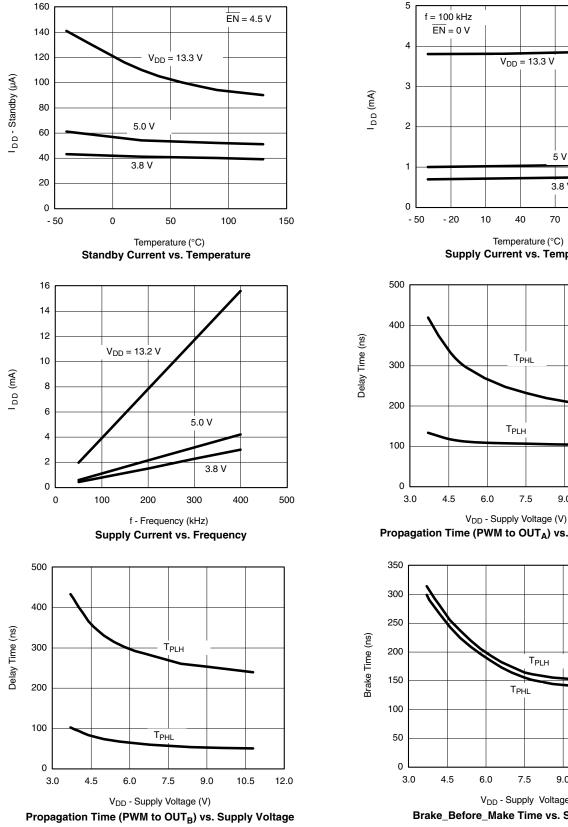
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Si9988







40 70 100 130 Temperature (°C) Supply Current vs. Temperature T_{PHL} T_{PLH}

5 V

3.8 V

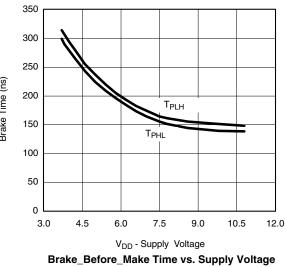
ISHA

Propagation Time (PWM to OUT_A) vs. Supply Voltage

9.0

10.5

12.0



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TIMING WAVEFORMS

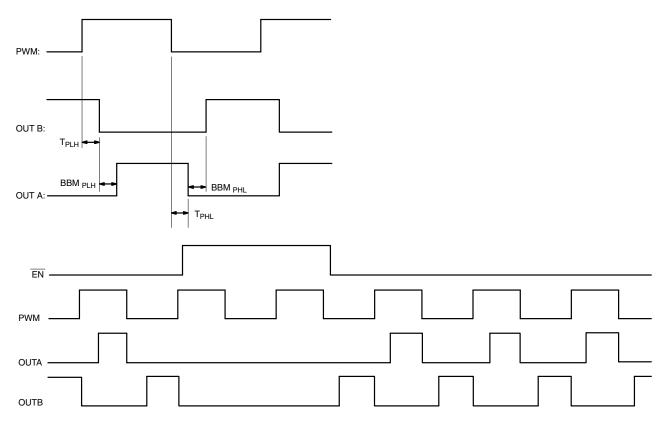


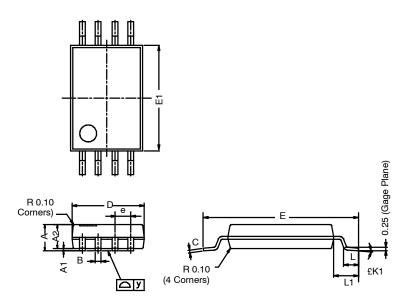
Figure 1.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?71326.



TSSOP: 8-LEAD (POWER IC ONLY)

JEDEC Part Number: MO-153



	MILLIMETERS					
Dim	Min	Nom	Max			
Α	-	-	1.20			
A ₁	0.05	0.10	0.15			
A ₂	0.80	1.00	1.05			
В	0.19	0.28	0.30			
С	-	0.127	-			
D	2.90	3.00	3.10			
Е	6.20	6.40	6.60			
E ₁	4.30	4.40	4.50			
е	-	0.65	-			
L	0.45	0.60	0.75			
L ₁	0.90	1.00	1.10			
Y	-	-	0.10			
£ K1	0 °	3°	6°			
ECN: S-40079—Rev. A, 02-Feb-04 DWG: 5908						



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